

APPENDIX B

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APPLICATION FOR LETTERS PATENT

for

**TECHNIQUE TO SIMULTANEOUSLY DISTRIBUTE
CLOCK SIGNALS AND DATA ON
INTEGRATED CIRCUITS, INTERPOSERS, AND CIRCUIT BOARDS**

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TITLE OF THE INVENTION

TECHNIQUE TO SIMULTANEOUSLY DISTRIBUTE CLOCK SIGNALS AND DATA ON
INTEGRATED CIRCUITS, INTERPOSERS, AND CIRCUIT BOARDS

BACKGROUND OF THE INVENTION

[0001] Field of the Invention: The present invention relates to the timing of clock and data signals in integrated circuits. More specifically, the invention relates to simultaneous transmission of digital data and clock signals to eliminate skewing of the data and clock signals with respect to each other.

[0002] State of the Art: Digital integrated circuits typically include multiple logic elements, with the timing of operation of each logic element controlled by a clock signal. It is common for an integrated circuit chip to have one central clock generator, with the signal from the clock generator being distributed around the integrated circuit via clock-line interconnects. An important consideration in the design of digital integrated circuits is the timing of the arrival of clock and data signals at various logic elements.

[0003] Variation in clock signal arrival time is referred to as clock skew. A variety of techniques have been used to provide clock connections that are symmetrical and all of the same length in order to minimize clock skew at the various logic elements, including, for example, the methods of Yip and Carrig. *See*, K. Yip, "Clock tree distribution: balance is essential for a deep-submicron ASIC design to flourish," IEEE Potentials, vol. 16, no. 2, pp. 11-14, Apr-May 1997; and K.M. Carrig et al., "Clock methodology for high-performance microprocessors," Proc. Custom Integrated Circuits Conference, Santa Clara, CA, May 5-8, pp. 119-122, 1997. A number of prior art approaches are illustrated in FIGS. 1A,- 1D.

[0004] Fig. 1A illustrates an H-tree clock-distribution, which is used primarily in custom layouts and has varying tree interconnect segment widths to balance skew throughout the chip.

[0005] FIG. 1B shows a clock grid clock-distribution structure. The clock grid is the simplest clock-distribution structure and has the advantage of being easy to design for low skew. However, it is area inefficient and power hungry because of the large amount of clock

interconnect required. Nevertheless, some chip vendors are using this clock structure for microprocessors.

[0006] FIG. 1C depicts a balanced tree clock-distribution structure. The balanced tree is the clock-distribution structure most commonly used in high performance chips. *See*, J.L. Neves et al., "Automated synthesis of skew-based clock-distribution networks," VLSI Design, vol. 7, no. 1, pp. 31-57, 1998. In order to carry current to the branching segments, the clock line is widest at the root of the tree and becomes progressively narrower at each branch. As a result, the clock line capacitance increases exponentially with distance from the leaf cell (clocked element) in the direction of the root of the tree (clock input). Moreover, additional chip area is required to accommodate the extra clock line width in the regions closer to the root of the tree.

[0007] As shown in FIG. 1D, buffers may be added at the branching points of the balanced tree structure. Adding buffers at the branching points of the tree significantly lowers clock interconnect capacitance, because it reduces the clock line width required toward the root.

[0008] One prior art alternative to generating clock signals centrally and distributing them about the chip is to partition the chip design into blocks, as shown in FIG. 2. A synchronous clock signal is used only within a single block, while communication between different blocks is performed on an asynchronous basis. *See*, T. Meincke et al., "Globally asynchronous locally synchronous architecture for large high-performance ASICs," IEEE Symposium On Circuits and Systems, Orlando, FL, 30 May-2 June, Vol. 2, pp. 512-515, 1999.

[0009] In the past, clock design has not typically been considered within the context of full chip timing. Existing design methodologies typically treat clock skew as a problem to be eliminated, and most designers strive to achieve zero skew. However, producing clock signals with zero skew may not be the optimum way to achieve either the safest or the highest performance clock design. It is often the case that, even after zero skew is attained, chip failures are caused by simultaneous switching current or other timing related problems.

[0010] There remains a need for a method of coordinating the timing of clock and data signals on a chip that can be achieved with a simple design and minimum number of critical paths on the chip. It would be desirable to reduce the power consumption associated with clock-distribution lines or other chip timing circuitry. It would also be desirable to reduce the sensitivity

of chip timing to process variations and various intermittent noises. Finally, there is an ongoing need for the development of higher speed methods for clocking data to provide enhanced chip performance.

BRIEF SUMMARY OF THE INVENTION

[0011] The methodology of the present invention addresses the problem of meeting a chip's timing requirements by combining clock timing with data path timing. Clock skew is treated not as a problem but as a controllable design variable which may be used to optimize overall chip timing. The invention achieves simultaneous distribution of clock and data signals by performing phase shift keying of digital data signals on clock frequency AC carrier signals, transmitting the keyed signals to different locations on the chip, and demodulating the keyed signals to retrieve digital data and clock signals. The inventive method may be used for signal interconnections on integrated circuits, interposers, and circuit boards.

[0012] The present invention reduces the number of critical paths on the chip in order to simplify designs and achieve timing closure. The present invention also allows increased clock frequency, thereby improving chip performance. Further, the present invention increases tolerance of chip timing to process variations and intermittent noise. The present invention may be used to create a larger timing budget to reduce power consumption. The present invention may also be used to reduce peak current and simultaneous switching noise to eliminate interference between digital and analog circuits.

BRIEF DESCRIPTION OF THE SEVERAL VIEWS OF THE DRAWINGS

[0013] In the drawings, which illustrate what is currently considered to be the best mode for carrying out the invention:

[0014] FIG. 1A shows a prior art H-tree clock-distribution structure;

[0015] FIG. 1B shows a prior art clock grid clock-distribution structure;

[0016] FIG. 1C shows a prior art balanced tree clock-distribution structure;

[0017] FIG. 1D shows a prior art balanced tree clock-distribution structure that includes buffers at branching points for reduction of clock-interconnect capacitance;

[0018] FIG. 2 illustrates a prior art method of partitioning a system into multiple blocks;

[0019] FIG. 3 is a block diagram of a device including circuitry for phase shift keying and demodulation of clock and digital data signals according to the present invention;

[0020] FIG. 4 is a block diagram depicting components of the inventive system used to perform differential Phase Shift Keying of digital data and clock signals;

[0021] FIG. 5 depicts a lead phase shift network used in the block diagram of FIG. 4;

[0022] FIG. 6 depicts a lag phase shift network used in the block diagram of FIG. 4;

[0023] FIG. 7A illustrates the signal $V_x = A \sin(\omega t + \phi)$ output by the lead phase shift network of FIG. 5;

[0024] FIG. 7B shows the signal $V_x = A \sin(\omega t - \phi)$ output by the lag phase shift network of FIG. 6;

[0025] FIG. 8 shows a demodulator circuit for recovering digital data from differential Phase Shift Keyed signals; and

[0026] FIG. 9 shows circuitry for recovering a clock signal from differential Phase Shift Keyed signals.

DETAILED DESCRIPTION OF THE INVENTION

[0027] In the present invention, analog signal techniques are used for signal interconnections on integrated circuits, interposers, and circuit boards. The clock signal is used as a high frequency carrier for signal interconnection and is modulated by the digital data using phase shift keying (PSK). PSK refers to a modulation technique that alters the phase of the carrier. Binary phase shift keying (BPSK), which is used in the present invention, has two phases, represented by the binary values 0 and 1. PSK is a special type of amplitude modulation, or a type of amplitude shift keying (ASK) which creates signals having values -1 or 1, and its bandwidth is the same as that of ASK. The inventive method includes the use of binary phase shift keying and low frequency differential modulation of the phase of a high frequency carrier. This approach results in a narrow bandwidth of the modulated signal comparable to that obtained with simple amplitude shift keying.

[0028] FIG. 3 is a block diagram of a device 2 including circuitry for performing phase shift keying of clock and digital data signals and subsequent demodulation of the PSK signals to retrieve the clock and digital data signals. Device 2 may be an integrated circuit, interposer, circuit board, or similar device. Device 2 includes phase shift keying circuitry 4, which performs phase shift keying of the digital data signal X onto the clock signal CLK to generate phase shift keyed signals V_x and $V_{\bar{x}}$. Phase shift keying circuitry 4 is located near the clock source on device 2. PSK signals V_x and $V_{\bar{x}}$ are transmitted on interconnection lines 9 and 13 to digital signal demodulator 6. Digital signal demodulator 6 demodulates PSK signals V_x and $V_{\bar{x}}$ to retrieve digital data signal X. Digital data signal X and PSK signals V_x and $V_{\bar{x}}$ are input to clock signal demodulator 8, which demodulates V_x and $V_{\bar{x}}$ to retrieve the clock signal. The clock signal and digital data signal X are input to clocked element 10 with no relative time delay between the two. Digital signal demodulator 6 and clock signal demodulator 8 are located close to clocked element 10 but may be located at some distance from phase shift keying circuitry 4.

[0029] Fig. 4 is a schematic diagram of differential phase shift keying circuitry 4 that may be used to perform the differential phase shift keying signal interconnection technique of the present invention. A sinusoidal oscillator signal $\sin(\omega t)$ having a radian frequency ω at the clock signal frequency for the chip is generated by oscillator 1. The oscillator signal is sent simultaneously to phase shifter 3 and phase shifter 5. Digital signal X is input to phase shifter 3 and controls the phase shift produced in the oscillator signal by phase shifter 3, while the complementary digital signal \bar{x} is input to and controls the phase shift produced in the oscillator signal by phase shifter 5. The output of phase shifter 3 is fed to driver amplifier 7 and, from there, transmitted on interconnection line 9. The output of phase shifter 5 is fed to driver amplifier 11 and subsequently transmitted on interconnection line 13. Interconnection line 9 and interconnection line 13 are low impedance interconnection lines with matched terminating impedances 15 and 17, respectively.

[0030] As shown in FIG. 5, phase shifter 3 is a lead phase shift network made up of capacitor 19 and voltage variable resistor 21 forming a high pass filter. Capacitor 19 has a capacitance C1 and voltage variable resistor 21 has a resistance of R1. Voltage variable resistor 21 is an NMOS transistor configured as a voltage variable resistor, with digital signal X

connected to its gate to regulate the value of resistance R1. Phase shifter 3 produces a positive phase shift ϕ in the input signal when X has a logical high value. Thus, when the input to phase shifter 3 is $\sin(\omega t)$ and X has a logical high value, the output will be $V_x = A\sin(\omega t + \phi)$, and when X has a logical low value, the output will be $V_x = A\sin(\omega t)$, where A is an arbitrary constant. V_x is plotted in FIG. 7A.

[0031] FIG. 6 depicts phase shifter 5, which is a lag phase shift network made up of voltage variable resistor 23 and capacitor 25 forming a low pass filter. Capacitor 25 has a capacitance C2 and voltage variable resistor 23 has a resistance of R2. Voltage variable resistor 23 is an NMOS transistor configured as a voltage variable resistor, with complementary digital input \bar{x} connected to its gate to regulate the value of resistance R2. Phase shifter 5 produces a phase shift of equal magnitude but opposite sign to that produced by phase shifter 3; thus it produces a negative phase shift ϕ in the input signal. Thus, when the input to phase shifter 5 is $\sin(\omega t)$ and \bar{x} has a logical high value, the output will be $V_{\bar{x}} = A\sin(\omega t - \phi)$, and when \bar{x} has a logical low value, the output will be $V_{\bar{x}} = A\sin(\omega t)$ where A is the arbitrary constant found in the expression for V_x . $V_{\bar{x}}$ is plotted in FIG. 7B.

[0032] Both phase shifter 3 and phase shifter 5 utilize phase shift networks of the type used in high frequency ring oscillators as disclosed in U.S. Patent application serial number 09/860,131, filed May 17, 2001, in which the frequency of oscillation can be near f_T of the transistors.

[0033] The phase shift keyed signals V_x and $V_{\bar{x}}$ are transmitted on matched interconnection lines 9 and 13 to the vicinity of the clocked element 10. V_x and $V_{\bar{x}}$ each contain both clock and phase shift keyed digital data. Any signal skew which occurs over the length of interconnection lines 9 and 13 should be substantially the same for the signals on the two interconnection lines. At the clocked element 10, signals V_x and $V_{\bar{x}}$ are demodulated to recover the digital signal X and the clock signal.

[0034] Digital signal demodulator 6, which is used to demodulate the digital signal encoded in signals V_x and $V_{\bar{x}}$, is depicted in FIG. 8. Digital signal demodulator 6 includes differential amplifier 27, transistor amplifier circuit 29 which functions as an inverter or single stage amplifier, RC filter 31, and comparator 33. Signals V_x and $V_{\bar{x}}$ are fed into the positive and

negative inputs, respectively, of a differential amplifier 27. The difference between V_x and V_x is $V_x - V_x = A\sin(\omega t + \phi) - A\sin(\omega t - \phi) = 2A\cos(\omega t)\sin(\phi)$ when X has a logical high value. When X has a logical low value, $V_x - V_x = 0$. As noted previously, A is an arbitrary constant amplitude, ω is the radian frequency of the carrier or oscillator frequency and ϕ is the amount of phase modulation at the input. Since ϕ , the amount of phase modulation, only has two values, zero and some finite value, then the differential output of the receiver is a pulse modulated sine or cosine wave at the carrier frequency.

[0035] Transistor amplifier circuit 29 is made up of diode-connected PMOS load transistor 35 and NMOS transistor 37. The demodulator circuit of FIG. 8 takes advantage of the nonlinear characteristics of PMOS load transistor 35 to recover digital data from PSK signals. For simplicity, it can be assumed that PMOS transistor 35 and NMOS transistor 37 have matching characteristics. Power supply voltage V_{DD} is connected to the source of PMOS transistor 35. Power supply voltage $V_{DD} = 4V_T$, where V_T is the threshold voltage of the PMOS transistor 35 and NMOS transistor 37. The nominal DC voltage at the output of differential amplifier 27 and the input of transistor amplifier circuit 29 is $2V_T$ when no AC signal is output by differential amplifier 27. The corresponding voltage at the output of transistor amplifier circuit 29 is also $2V_T$. When V_x and V_x are applied to the inputs of differential amplifier 27, the output is: $V_1 = 2V_T + 2A\cos(\omega t)\sin(\phi)$ when X has a logical high value and $V_1 = 2V_T$ when X has a logical low value.

[0036] If the signal amplitude $2A$ is made comparable to V_T of the transistors, the output from transistor amplifier circuit 29 is:

$$V_2 = 2V_T - 2A\cos(\omega t)\sin(\phi) - [4A^2/(4V_T)]\cos^2(\omega t)\sin^2(\phi),$$

which, as can be seen, includes a component that depends on the square of the AC component of the input signal.

[0037] RC filter 31, which is a simple RC low pass filter at the output of transistor amplifier circuit 29, is made up of resistor 39 having a resistance R3 and capacitor 41 having a capacitance C3. The output of RC filter 31 is:

$$V_3 = 2V_T - \frac{1}{2}[(4A^2/(4V_T))\sin^2(\phi)],$$

which is the DC component of the output of transistor amplifier circuit 29 and corresponds to the average value of cosine squared. Signal V_3 is input to comparator 33 and compared to reference signal $V_{ref} = 2V_T$ to produce an output signal V_4 which has a value of either $\sin^2(\varphi)$ or zero. V_4 is the recovered digital data signal.

[0038] FIG. 9 illustrates the circuitry of clock signal demodulator 8, which is used to recover the clock signal from the modulated RF carrier. Also shown are matched output impedances 15 and 17 of interconnection lines 9 and 13, respectively.

[0039] Clock signal demodulator 8 includes two phase shift networks, lag phase shift network 43 and lead phase shift network 45. Lag phase shift network 43 includes a low pass filter made up of voltage variable resistor 47 having resistance R_4 and capacitor 49 having resistance C_4 . The input to lag phase shift network 43 is signal V_x from interconnection line 9. Voltage variable resistor 47 is an NMOS transistor configured as a voltage variable resistor. The resistance R_4 of voltage variable resistor 47 is controlled by voltage V_5 , which is connected to the gate of the NMOS transistor. $V_5 = V_{DC} - BV_4$, where V_{DC} is a constant DC voltage, B is an arbitrary constant, and V_4 is the recovered digital signal output by the demodulator circuit shown in FIG. 8. The output of lag phase shift network 43 is fed into driver amplifier 51. The output of driver amplifier 51 is $V_7 = D\sin(\omega t + \varphi - \theta)$, where D is an arbitrary constant, ω is the radian frequency of the clock signal, φ is the phase shift introduced by phase shifter 3 during phase shift keying of the digital data, and θ is the phase shift introduced by lag phase shift network 43.

[0040] Lead phase shift network 45 includes a high pass filter made up of capacitor 53 having capacitance C_5 and voltage variable resistor 55 having resistance R_5 . The input to lead phase shift network 45 is signal V_x from interconnection line 13. Voltage variable resistor 55 is an NMOS transistor configured as a voltage variable resistor. The resistance R_5 of voltage variable resistor 55 is controlled by voltage V_6 , which is connected to the gate of the NMOS transistor. $V_6 = V_{DC} + BV_4$, where V_{DC} , B , and V_4 are as defined previously. The output of lead phase shift network 45 is fed into driver amplifier 57. The output of driver amplifier 57 is $V_8 = D\sin(\omega t - \varphi + \theta)$, where D is the same arbitrary constant as found in the equation for V_7 , ω is the radian frequency of the clock signal, φ is the phase shift introduced by phase shifter 5 during

phase shift keying of the digital data, and θ is the phase shift introduced by lead phase shift network 45.

[0041] In lag phase shift network 43 and lead phase shift network 45, changing the resistance values R_4 and R_5 changes the phase shift of each network. In lead phase shift network 45, decreasing R_5 increases the phase shift θ , making it more positive, since the corner frequency, ω_c , moves up closer to the carrier frequency, ω . In lag phase shift network 43, increasing R_4 lowers the corner frequency ω_c and makes θ more negative, or shifts the phase of the incoming signal to more negative values.

[0042] The gains and characteristics of lag phase shift network 43 and lead phase shift network 45 are adjusted so that $\varphi = \theta$. An analog adder 59 made up of resistors 61, 63, and 65 and amplifier 67 is used to average signals V_7 and V_8 to reduce noise and errors and yield output V_9 , which equals the clock signal $\sin(\omega t)$ without the modulation of the digital data. In this manner, the clock signal can be recovered.

[0043] The frequency limiting element in this system is not the oscillator, carrier frequency, digital modulation frequency, or line characteristics but, rather, is likely to be the receiver amplifier. By using a relatively small number of CMOS elements in the circuitry of the invention, power consumption is kept low. The novel PSK method allows clock and data signals to be transmitted over any distance and to remain synchronized with each other. Speed and performance of the device is thus enhanced.